

BCR5AS-12A

600V - 5A - Triac

Medium Power Use

R07DS1441EJ0500
(Previous: REJ03G0289-0400)
Rev.5.00
May. 10, 2019

Features

- $I_T (RMS)$: 5 A
- V_{DRM} : 600 V
- I_{FGT} , I_{RGT} , $I_{RGT III}$: 30 mA
- T_j : 125 °C
- Planar Passivation Type

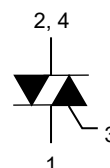
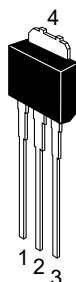
Outline

RENESAS Package code: PRSS0004ZG-A

(Package name: MP-3A)

PRSS0004ZD-D

(Package name: DPAK(L)-(3))



1. T_1 Terminal
2. T_2 Terminal
3. Gate Terminal
4. T_2 Terminal

Application

Small motor control, heater control, and other general purpose AC control applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	720	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_T (RMS)$	5	A	Commercial frequency, sine full wave 360°conduction, $T_c = 103^\circ\text{C}$ ^{Note3}
Surge on-state current	I_{TSM}	50	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusing	I^2t	10.4	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	3	W	
Average gate power dissipation	$P_{G(AV)}$	0.3	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	T_j	-40 to +125	°C	
Storage temperature	T_{stg}	-40 to +125	°C	

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak off-state current	I_{DRM}	—	—	2.0	mA	$T_J = 125^{\circ}\text{C}$, V_{DRM} applied
On-state voltage	V_{TM}	—	—	1.8	V	$T_C = 25^{\circ}\text{C}$, $I_{TM} = 7\text{ A}$, instantaneous measurement
Gate trigger voltage ^{Note2}	I V_{FGTI}	—	—	1.5	V	$T_J = 25^{\circ}\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II V_{RGTI}	—	—	1.5	V	
	III V_{RGTIII}	—	—	1.5	V	
Gate trigger current ^{Note2}	I I_{FGTI}	—	—	30	mA	$T_J = 25^{\circ}\text{C}$, $V_D = 6\text{ V}$, $R_L = 6\ \Omega$, $R_G = 330\ \Omega$
	II I_{RGTI}	—	—	30	mA	
	III I_{RGTIII}	—	—	30	mA	
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_J = 125^{\circ}\text{C}$, $V_D = 1/2 V_{DRM}$
Thermal resistance	$R_{th(j-c)}$	—	—	3.0	$^{\circ}\text{C/W}$	Junction to case ^{Note3}
Critical-rate of rise of off-state commutating voltage ^{Note4}	$(dv/dt)_c$	5	—	—	$\text{V}/\mu\text{s}$	$T_J = 125^{\circ}\text{C}$

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

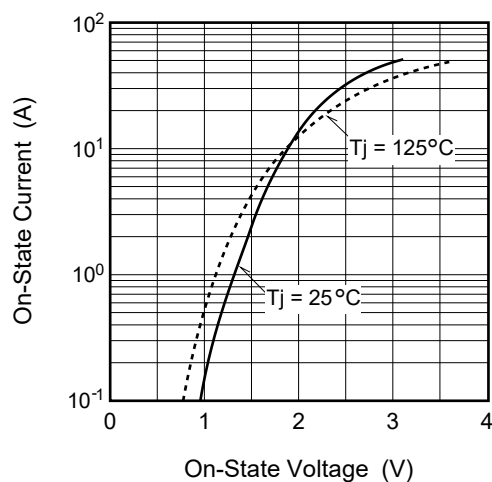
3. Case temperature is measured on the T_2 tab.

4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

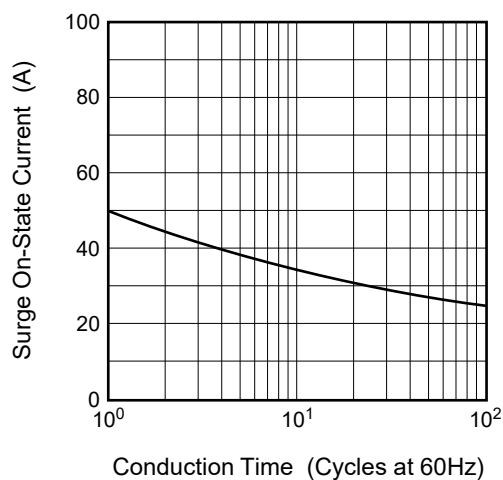
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_J = 125^{\circ}\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c = -2.5\text{ A/ms}$ 3. Peak off-state voltage $V_D = 400\text{ V}$	

Performance Curves

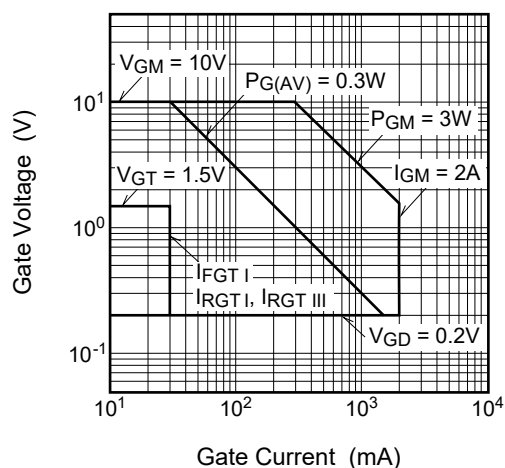
Maximum On-State Characteristics



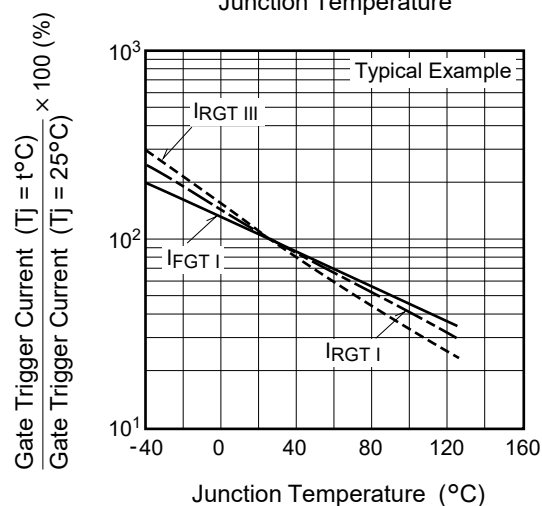
Rated Surge On-State Current



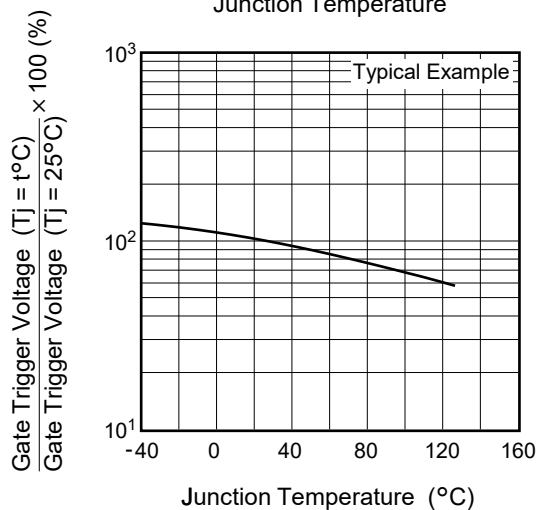
Gate Characteristics (I, II and III)



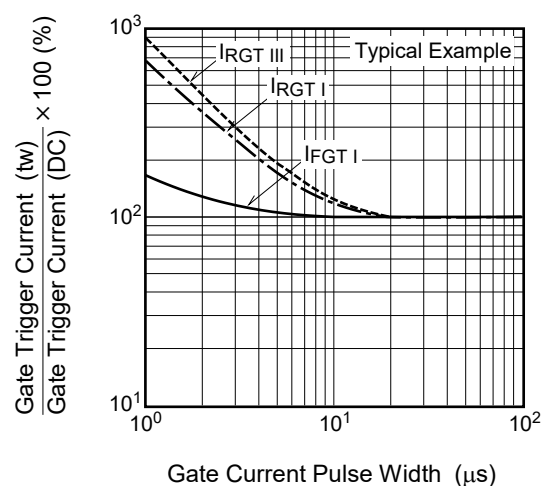
Gate Trigger Current vs. Junction Temperature

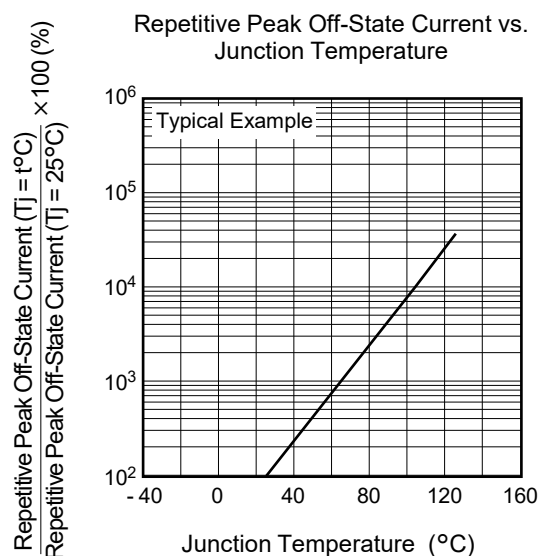
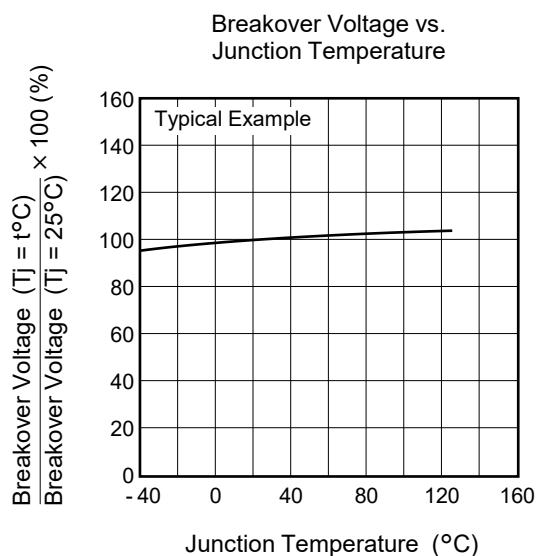
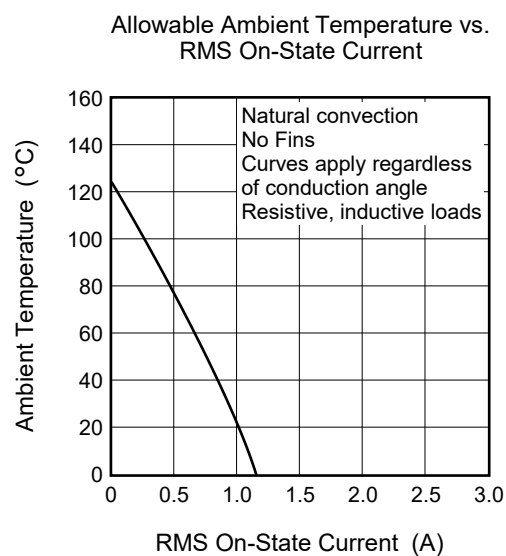
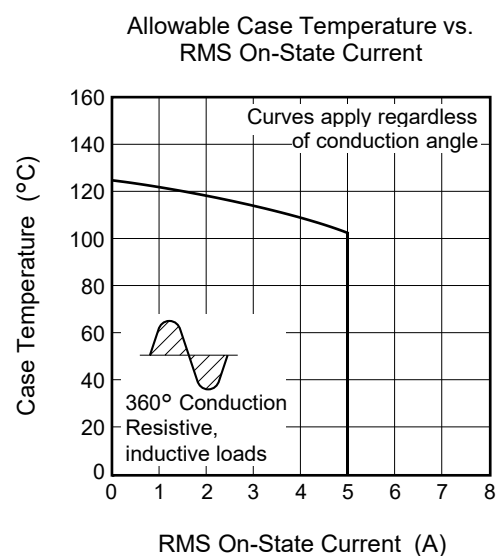
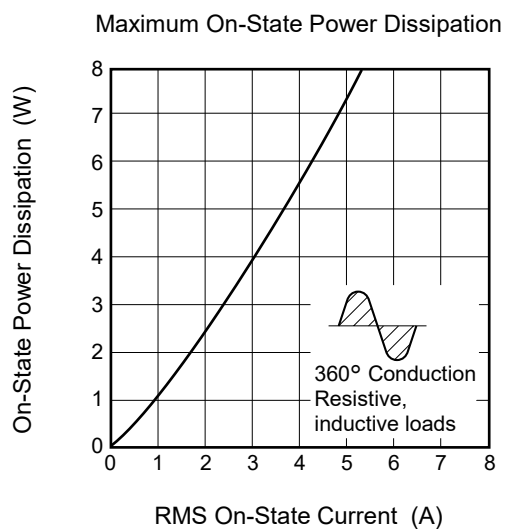
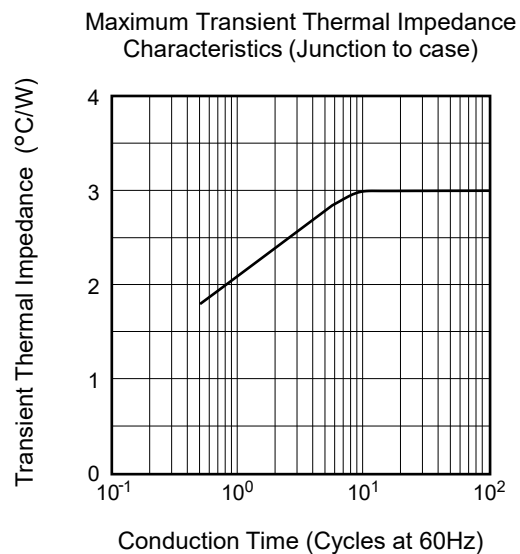


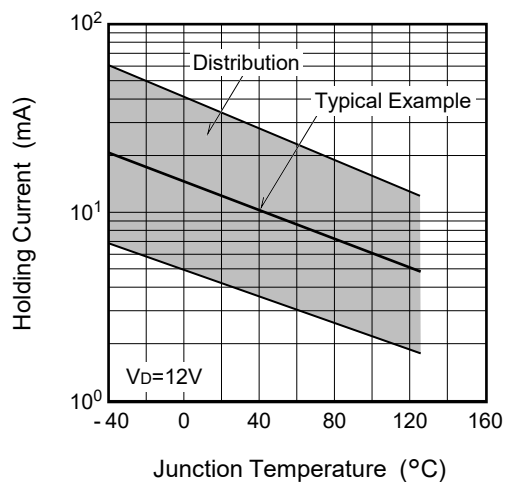
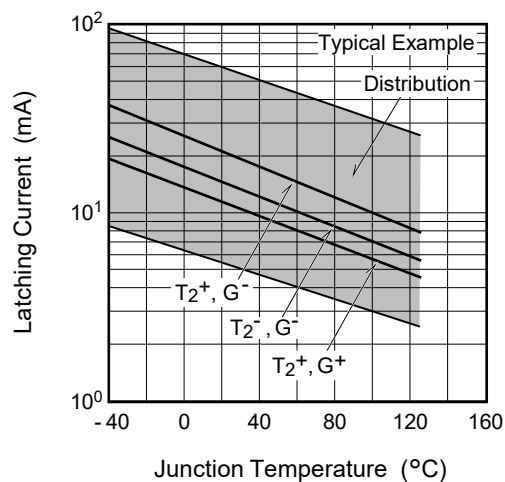
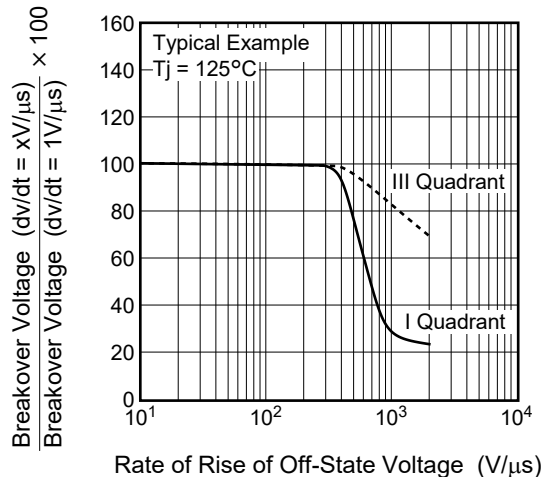
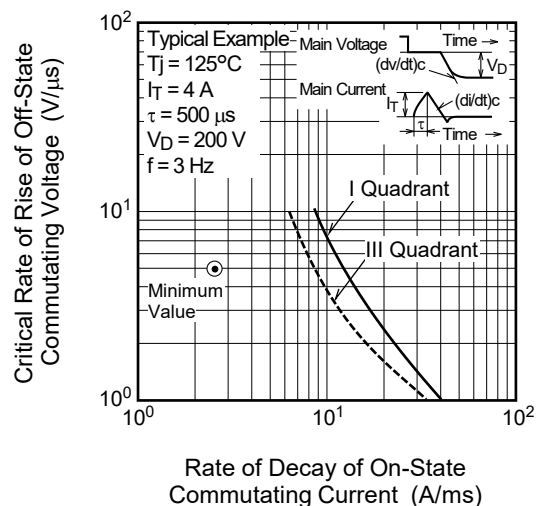
Gate Trigger Voltage vs. Junction Temperature



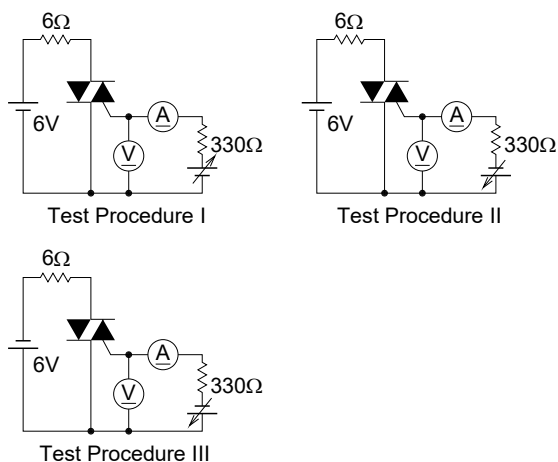
Gate Trigger Current vs. Gate Current Pulse Width





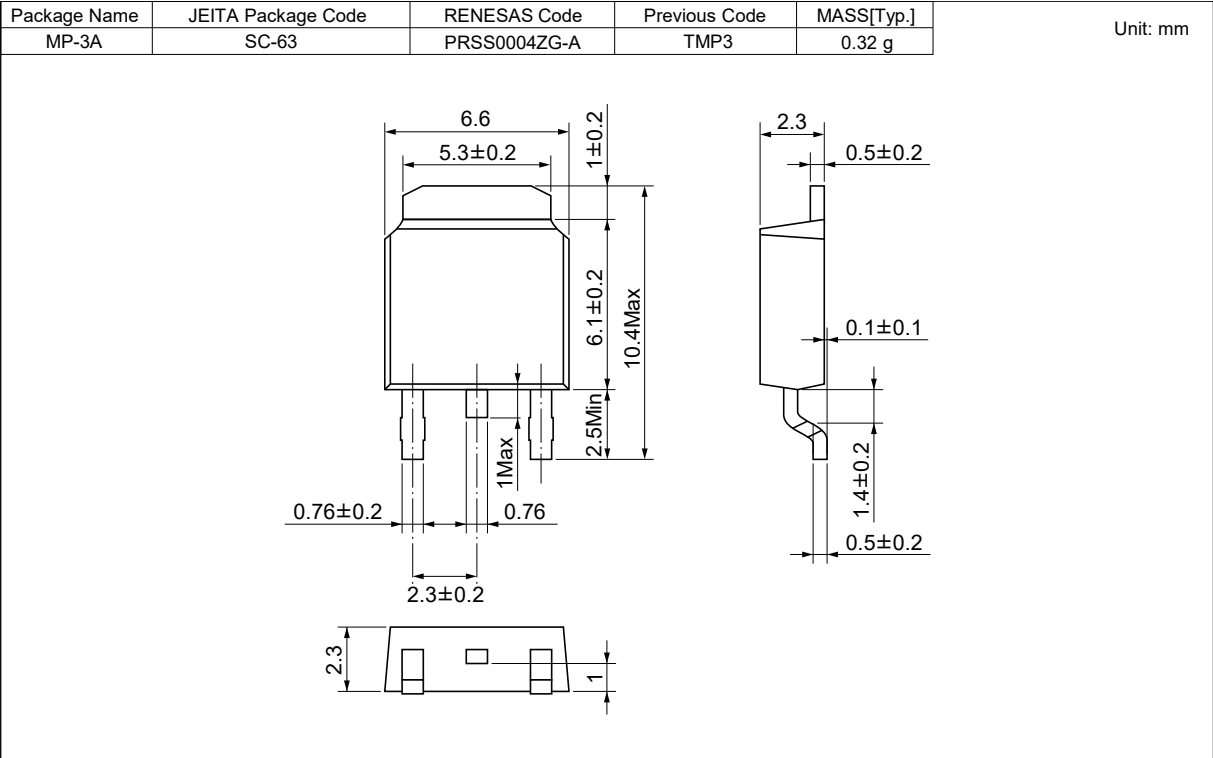
Holding Current vs.
Junction TemperatureLatching Current vs.
Junction TemperatureBreakover Voltage vs.
Rate of Rise of Off-State Voltage ($T_J = 125^{\circ}\text{C}$)Commutation Characteristics ($T_J = 125^{\circ}\text{C}$)

Gate Trigger Characteristics Test Circuits

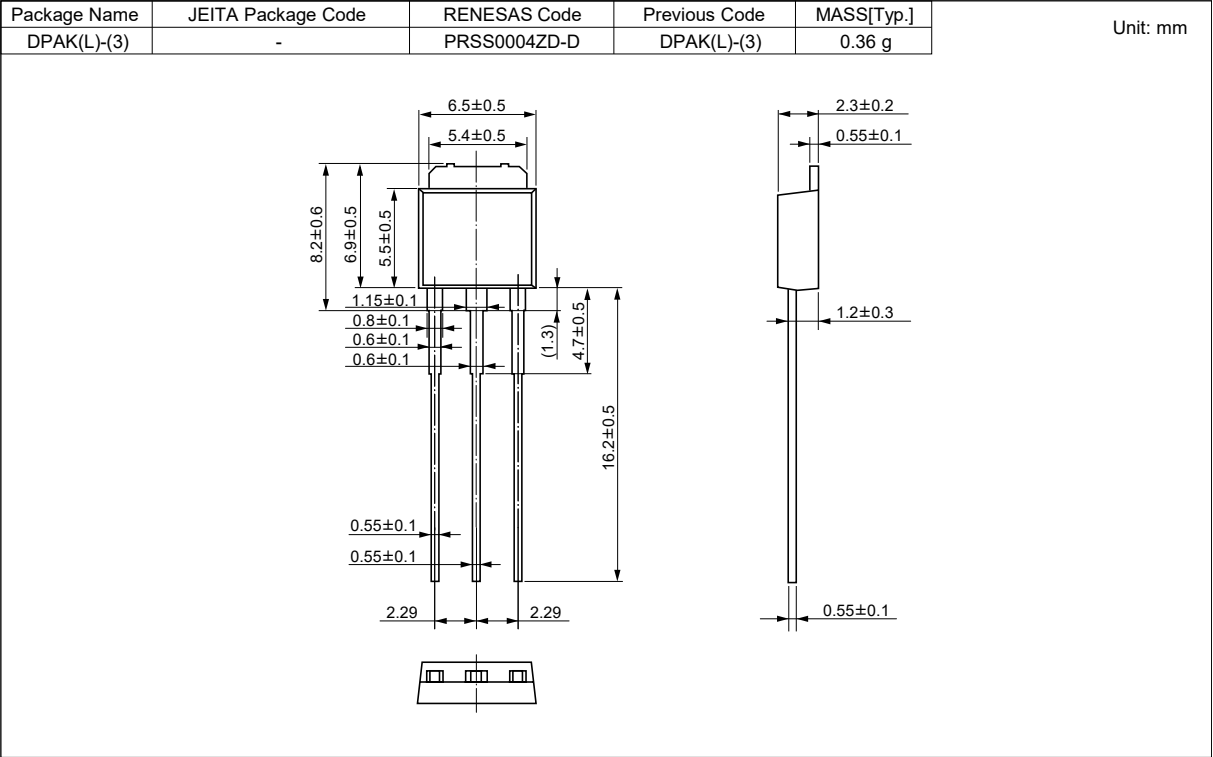


Package Dimensions

Package Name: MP-3A



Package Name: DPAK(L)-(3)



Ordering Information

Orderable Part Number	Package	Packing ^{Note5}	Quantity	Remark
BCR5AS-12A-T13#B00	MP-3A	Embossed tape	3000 pcs.	
BCR5AS-12A#B00	MP-3A	Tube	75 pcs.	Tube packing is to be abolished.
BCR5AS-12A-A1#B00	DPAK(L)-(3)	Tube	80 pcs.	

Note: 5. Please confirm the specification about the shipping in detail.

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(Rev.4.0-1 November 2017)



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